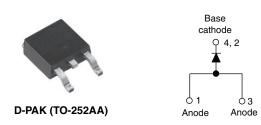
**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 10 A



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PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I <sub>F(AV)</sub>	10 A					
V <sub>R</sub>	45 V					
V <sub>F</sub> at I <sub>F</sub>	0.57 V					
I <sub>RM</sub>	15 mA at 125 °C					
T <sub>J</sub> max.	175 °C					
Diode variation	Single die					
E <sub>AS</sub>	20 mJ					

## FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long | term reliability
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-STPS1045B-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	10	А						
V <sub>RRM</sub>		45	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	390	А						
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V						
TJ	Range	-40 to +175	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-STPS1045B-M3	UNITS						
Maximum DC reverse voltage	V <sub>R</sub>	45	V						
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	v						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 151 °C	10						
Maximum peak one cycle non-repetitive surge current			Following any rated load condition and with rated	390	А				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	75					
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 3.0 \text{ A}, L = 4.40$	20	mJ					
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by T <sub>J</sub> maxim	3.0	А					

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 1
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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS						
		10 A	T <sub>.1</sub> = 25 °C	0.63	V				
Maximum forward voltage drop	V <sub>EM</sub> <sup>(1)</sup>	20 A	1j=23 0	0.84					
See fig. 1	VFM (")	10 A	T = 125 °C	0.57					
		20 A	T <sub>J</sub> = 125 °C	0.72					
Maximum reverse leakage current	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.2	mA				
See fig. 2	IRM (1)	T <sub>J</sub> = 125 °C	VR = haleu VR	15					
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	760	pF					
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm	5.0	nH					
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs					

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

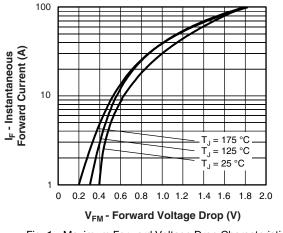
THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER SYMBOL TEST CONDITIONS VALUES U									
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-40 to +175	°C					
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	3.0	°C/W					
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>		50	C/W					
Approximate weight			0.3	g					
Approximate weight			0.01	oz.					
Marking device		Case style D-PAK (similar to TO-252AA)	STPS10	045B					

### Note

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

# **VS-STPS1045B-M3**

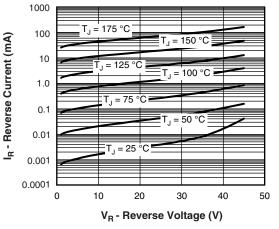
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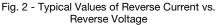


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Fig. 1 - Maximum Forward Voltage Drop Characteristics





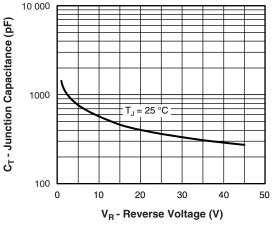


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

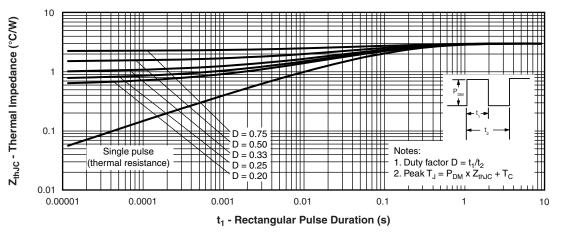


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

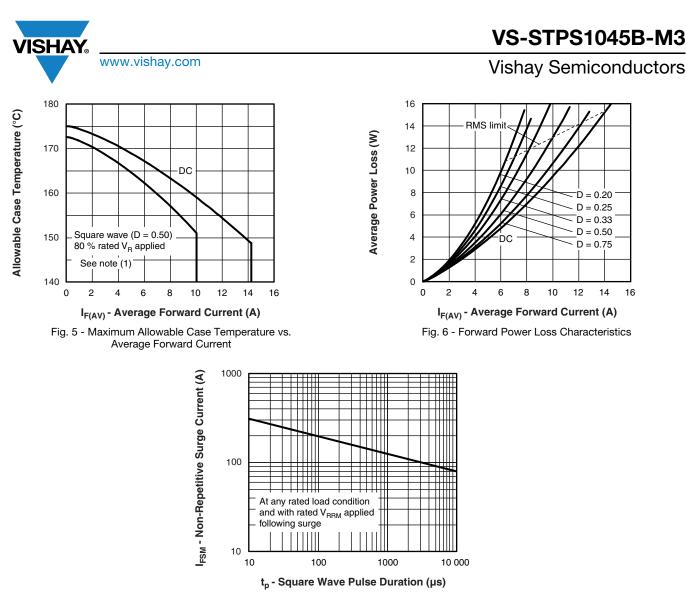


Fig. 7 - Maximum Non-Repetitive Surge Current

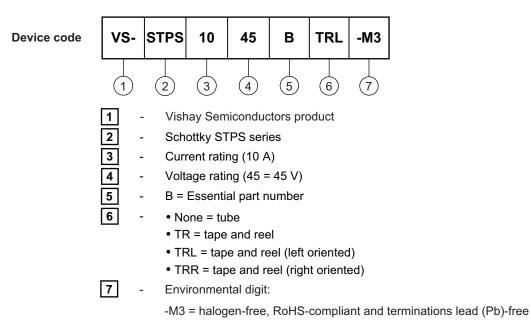
#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R at V_{R1} = 80 \%$  rated  $V_R$ 

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## **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)									
PREFERRED P/N         QUANTITY PER T/R         MINIMUM ORDER QUANTITY         PACKAGING									
VS-STPS1045B-M3	75	3000	Antistatic plastic tube						
VS-STPS1045BTR-M3	2000	2000	13" diameter reel						
VS-STPS1045BTRL-M3	3000	3000	13" diameter reel						
VS-STPS1045BTRR-M3	3000	3000	13" diameter reel						

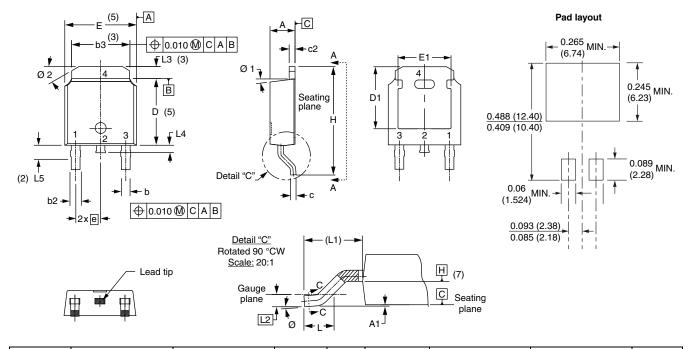
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95627					
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					





D-PAK (TO-252AA) "M"

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES				SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA

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